SIC SCHOTTKY DIODE TYPE 2×50A

Temperature Independent Switching Behavior

1700 V

2×50 A

DACO SEMICONDUCTOR CO., LTD. CSRI2×50-170P1B

Preliminary

SOT-227

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1

Features

- High surge current capable
- Zero reverse recovery
- Zero forward recovery
- Isolation type package

Benefits

- Unipolar rectifier
- Smaller heat sink

Applications

- Motor drives
- Switch mode power supplies
- Ev chargers
- Solar inverters
- Welding equipment
- Power factor correction
- Diode snubber

• VDC

• IF (Tc<135°C)

Higher efficiency

- Automotive
- induction heating

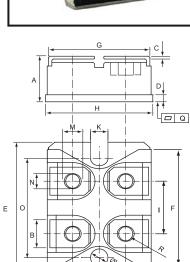
Maximum Ratings

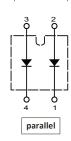
Operating Junction Temperature : - 55 $^\circ\!C$ to +175 $^\circ\!C$

Storage Temperature : -55 $^{\circ}$ C to +175 $^{\circ}$ C

Part Number	Maximum Recurrent Peak Reverse Voltage	Maximum DC Blocking Voltage
CSRI2×50-170P1B	1700V	1700V

Maximum Rating	Symbol	Conditions	Value	Unit	
Continuous forward current (per diode)	I _F	T _C =135 °C	50		
Surge non-repetitive forward current	I _{FSM}	T _C =25 °C, t _p =8.3 ms	400		
sine halfwave (per diode)	IFSM	T _C =150 °C, t _p =8.3 ms	250	А	
Non-repetitive peak forward current	I _{F,max}	T _C =25 °C, t _p =10 μ s	1600		
(per diode)		T _C =150 °C, t _p =10 μ s	1000		
Repetitive peak reverse voltage	V _{RRM}	T _j =25 °C	1700	V	
Isolation voltage between all terminals and baseplate	V _{iso}	V_{iso} 50/60 Hz, t=1min $I_{ISOL} \le 1mA$		V	
Mounting torque		To heatsink	1.3	Nm	
		To terminal	1.1		





DIMENSIONS						
	INC	HES	MM			
	MIN	MIN MAX MIN		MAX		
А	0.460	0.483	11.68	12.28		
В	0.307	0.323	7.80	8.20		
С	0.030	0.033	0.75	0.85		
D	0.071	0.081	1.80	2.05		
E	1.488	1.504	37.80	38.20		
F	1.248	1.260	31.70	32.00		
G	0.917	0.957	23.30	24.30		
Н	0.996	1.008	25.30	25.60		
Ι	0.579	0.602	14.70	15.30		
J	0.492	0.516	12.50	13.10		
K	0.161	0.169	4.10	4.30		
L	0.161	0.169	4.10	4.30		
М	0.181	0.197	4.60	5.00		
Ν	0.165	0.181	4.20	4.60		
0	1.181	1.197	30.00	30.40		
Q	-0.002	0.004	-0.05	0.10		
R		M4*8				

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Electrical Characteristics, at T_j =25 °C, unless otherwise specified. (per diode)

Static Characteristics	Symbol	Conditions	Values			
			min.	typ.	max.	Unit
DC blocking voltage	V _{DC}		1,700	-	-	V
Diode forward voltage	V _F	I _F =50A, T _j =25 °C	-	1.6	1.8	V
		I _F =50A, T _j =175 °C	-	2.4	2.9	
Reverse current	I _R	V _R =1,700V, T _j =25 °C	-	30	60	μΑ
		V _R =1,700V, T _j =175 °C	-	60	250	

AC Characteristics (per diode)

Static Characteristics	Symbol	Conditions	Values			
			min.	typ.	max.	Unit
Total capacitive charge	Q _{rr}	V _R =800V I _F =50A, T _j =25 °C	-	133.9	-	nC
Total capacitance	С	V _R =0V, f=1 MHz T _j =25 °C	-	2,874	-	pF
		V _R =800V, f=1 MHz T _j =25 °C	-	200	-	
		V _R =1000V, f=1 MHz T _j =25 °C	-	199	-	

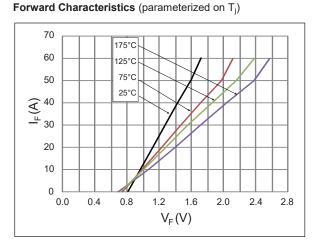
Thermal Characteristics (per diode)

Statia Characteristica	Sympol	Values		
Static Characteristics	Symbol	typ.	Unit	
Thermal resistance from junction to case	$R_{ heta JC}$	0.28	°C/W	

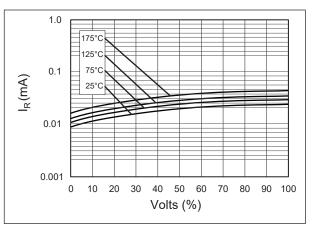


CSRI2×50-170P1B

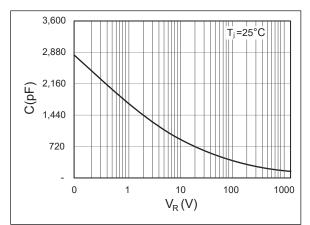
Typical Performance



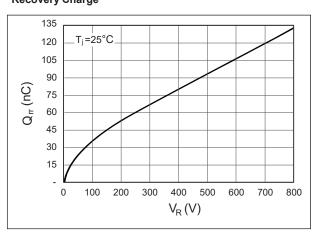
Reverse Characteristics (parameterized on Tj)



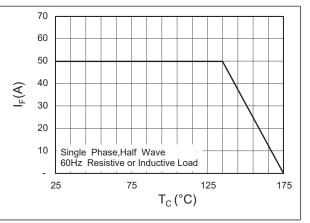
Capacitance

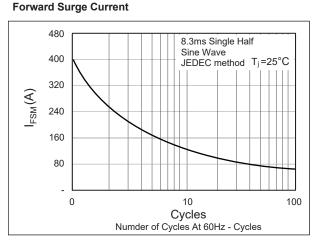


Recovery Charge











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